

# **NSVBC857CWT1G Datasheet**

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DiGi Electronics Part Number	NSVBC857CWT1G-DG
Manufacturer	onsemi
Manufacturer Product Number	NSVBC857CWT1G
Description	TRANS PNP 45V 0.1A SC70-3
Detailed Description	Bipolar (BJT) Transistor PNP 45 V 100 mA 100MHz 1 50 mW Surface Mount SC-70-3 (SOT323)

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## Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
NSVBC857CWT1G	onsemi
Series:	Product Status:
	Active
Transistor Type:	Current - Collector (Ic) (Max):
PNP	100 mA
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
45 V	650mV @ 5mA, 100mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ lc, Vce:
15nA (ICBO)	420 @ 2mA, 5V
Power - Max:	Frequency - Transition:
150 mW	100MHz
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Surface Mount
Package / Case:	Supplier Device Package:
SC-70, SOT-323	SC-70-3 (SOT323)
Base Product Number:	
NSVBC857	

## **Environmental & Export classification**

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8541.21.0075	

# onsemi

# General Purpose Transistors

### **PNP Silicon**

# BC856B, BC857B, BC858A

These transistors are designed for general purpose amplifier applications. They are housed in the SC-70/SOT-323 which is designed for low power surface mount applications.

#### Features

- S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Rating	Symbol	Value	Unit
Collector-Emitter Voltage BC856 BC857 BC858	V <sub>CEO</sub>	-65 -45 -30	V
Collector-Base Voltage BC856 BC857 BC858	V <sub>CBO</sub>	-80 -50 -30	V
Emitter-Base Voltage	V <sub>EBO</sub>	-5.0	V
Collector Current – Continuous	Ι <sub>C</sub>	-100	mAdc
Collector Current – Peak (1 ms pulse)	I <sub>CM</sub>	-130	mA

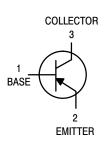
#### **MAXIMUM RATINGS** (T<sub>A</sub> = $25^{\circ}$ C unless otherwise noted)

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR- 5 Board, (Note 1) $T_A = 25^{\circ}C$	PD	150	mW
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	883	°C/W
Junction and Storage Temperature	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1.  $FR-5 = 1.0 \times 0.75 \times 0.062$  in.





#### MARKING DIAGRAM



XX = Specific Device Code M = Date Code\* = Pb-Free Package

(Note: Microdot may be in either location) \*Date Code orientation may vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 5 of this data sheet.

### BC856B, BC857B, BC858A

#### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS						
Collector – Emitter Breakdown Voltage $(I_C = -10 \text{ mA})$	BC856 BC857 BC858	V <sub>(BR)CEO</sub>	-65 -45 -30	- - -	- - -	V
Collector – Emitter Breakdown Voltage ( $I_C = -10 \ \mu$ A, $V_{EB} = 0$ )	BC856 BC857 BC858	V <sub>(BR)CES</sub>	-80 -50 -30	- - -	- - -	V
Collector – Base Breakdown Voltage ( $I_C = -10 \ \mu A$ )	BC856 BC857 BC858	V <sub>(BR)CBO</sub>	-80 -50 -30	- - -	- - -	V
Emitter – Base Breakdown Voltage ( $I_E = -1.0 \ \mu A$ )	BC856 BC857 BC858	V <sub>(BR)EBO</sub>	-5.0 -5.0 -5.0	- - -	- - -	V
Collector Cutoff Current (V <sub>CB</sub> = $-30$ V) (V <sub>CB</sub> = $-30$ V, T <sub>A</sub> = $150^{\circ}$ C)		I <sub>CBO</sub>			-15 -4.0	nA μA

#### **ON CHARACTERISTICS**

			1		1	
DC Current Gain	BC856A, BC585A	h <sub>FE</sub>	-	90	-	-
(I <sub>C</sub> = −10 μA, V <sub>CE</sub> = −5.0 V)	BC856B, BC857B, BC858B		-	150	-	
	BC857C		-	270	-	
(I <sub>C</sub> = −2.0 mA, V <sub>CE</sub> = −5.0 V)	BC856A, BC858A		125	180	250	
	BC856B, BC857B, BC858B		220	290	475	
	BC857C		420	520	800	
Collector – Emitter Saturation Voltage		V <sub>CE(sat)</sub>				V
(I <sub>C</sub> = –10 mA, I <sub>B</sub> = –0.5 mA)		( )	-	-	-0.3	
(I <sub>C</sub> = -100 mA, I <sub>B</sub> = -5.0 mA)			-	-	-0.65	
Base – Emitter Saturation Voltage		V <sub>BE(sat)</sub>				V
(I <sub>C</sub> = –10 mA, I <sub>B</sub> = –0.5 mA)		. ,	-	-0.7	-	
(I <sub>C</sub> = –100 mA, I <sub>B</sub> = –5.0 mA)			-	-0.9	-	
Base – Emitter On Voltage		V <sub>BE(on)</sub>				V
(I <sub>C</sub> = –2.0 mA, V <sub>CE</sub> = –5.0 V)		( )	-0.6	-	-0.75	
$(I_{C} = -10 \text{ mA}, V_{CE} = -5.0 \text{ V})$			-	-	-0.82	

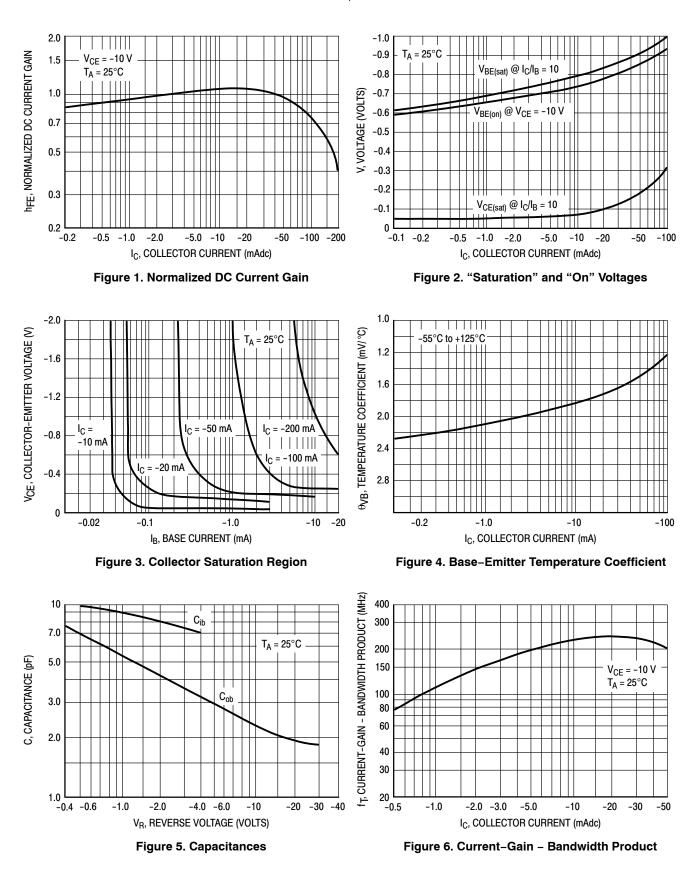
#### SMALL-SIGNAL CHARACTERISTICS

Current – Gain – Bandwidth Product ( $I_C = -10 \text{ mA}, V_{CE} = -5.0 \text{ Vdc}, f = 100 \text{ MHz}$ )	f <sub>T</sub>	100	-	-	MHz
Output Capacitance (V <sub>CB</sub> = -10 V, f = 1.0 MHz)	C <sub>ob</sub>	_	-	4.5	pF
Noise Figure (I <sub>C</sub> = $-0.2$ mA, V <sub>CE</sub> = $-5.0$ Vdc, R <sub>S</sub> = $2.0$ kΩ, f = $1.0$ kHz, BW = $200$ Hz)	NF	-	-	10	dB

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

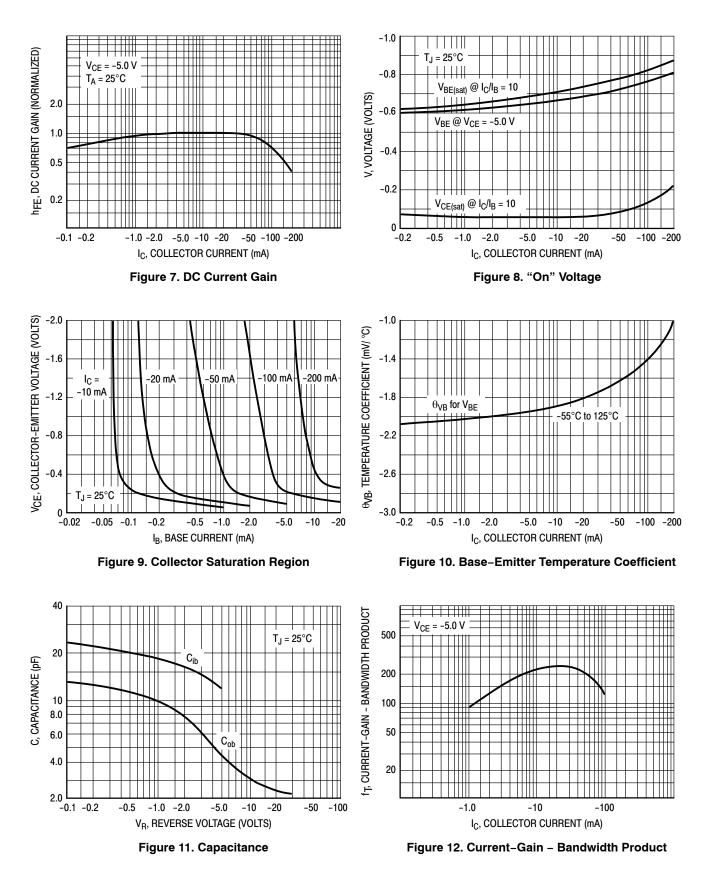


BC857/BC858

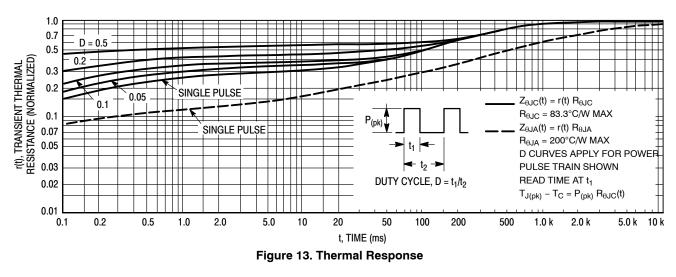








BC856B, BC857B, BC858A



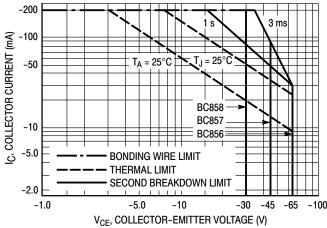


Figure 14. Active Region Safe Operating Area

The safe operating area curves indicate  $I_C-V_{CE}$  limits of the transistor that must be observed for reliable operation. Collector load lines for specific circuits must fall below the limits indicated by the applicable curve.

The data of Figure 14 is based upon  $T_{J(pk)} = 150^{\circ}$ C;  $T_{C}$  or  $T_{A}$  is variable depending upon conditions. Pulse curves are valid for duty cycles to 10% provided  $T_{J(pk)} \le 150^{\circ}$ C.  $T_{J(pk)}$  may be calculated from the data in Figure 13. At high case or ambient temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by the secondary breakdown.

Device	Marking	Package	Shipping <sup>†</sup>	
BC856BWT1G	0.0	SC-70/SOT-323	0.000 / Tara & Daal	
SBC856BWT1G*		(Pb-Free)	3,000 / Tape & Reel	
BC857BWT1G	3F	SC-70/SOT-323	2 000 / Tana & Daal	
SBC857BWT1G*	3F	(Pb-Free)	3,000 / Tape & Reel	
BC857CWT1G	20	SC-70/SOT-323	2 000 / Tana & Daal	
NSVBC857CWT1G*		(Pb-Free)	3,000 / Tape & Reel	
BC858AWT1G	ЗJ	SC-70/SOT-323 (Pb-Free)	3,000 / Tape & Reel	
BC858BWT1G	ЗК	SC-70/SOT-323 (Pb-Free)	3,000 / Tape & Reel	

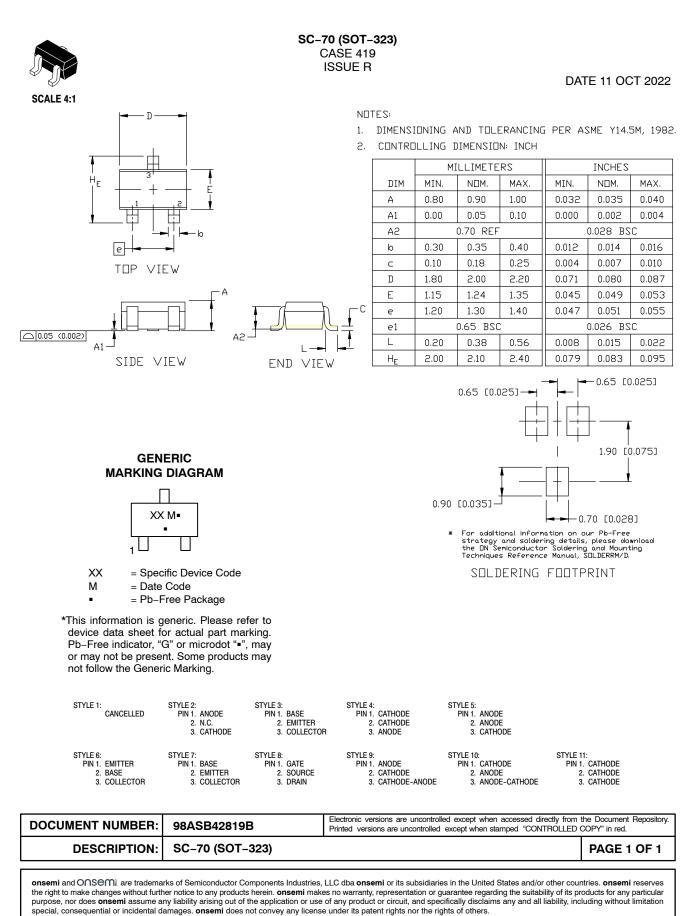
#### ORDERING INFORMATION

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable.

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PACKAGE DIMENSIONS



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